NSN 5962-01-546-3434

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View Online at https://aerobasegroup.com/nsn/5962-01-546-3434

Body	Lon	ath.
DOUV	Len	atn.

Between 0.706 inches and 0.718 inches

Body Width:

Between 0.340 inches and 0.350 inches

Body Height:

Between 0.086 inches and 0.090 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Nha pn 747-3120-012 cage 78711 e/i c-17a aircraft

Features Provided:

Electrostatic sensitive

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Current Rating Per Characteristic:

65.00 milliamperes reverse current, dc absolute

Product Name:

Microcircuit, 8 k x 8 nvsram

Voltage Rating And Type Per Characteristic:

4.5 volts power source and 5.5 volts power source

Capitance Rating Per Characteristic:

8.00 input picofarads and 7.00 output picofarads

Time Rating Per Chacteristic:

45.00 nanoseconds access

Memory Device Type:

Ram

Memory Capacity:

8 k x 8

Special Features:

Nonvolatile ram,

Terminal Type And Quantity:

28 gullwing

Shelf Life:

N/a

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In	18	<i>(</i>)+	МА	261	ıre:

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Demilitarization:

Yes - demil/mli

Fiig:

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